

# SIC SCHOTTKY DIODE TYPE 2×50A

# **Features**

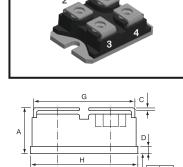
- High surge current capable
- Zero reverse recovery current VDC
- High bandwidth
- Isolation type package
- Temperature Independent Switching Behavior
- 650 V
- 2×50 A • **I**F (Tc<135°C)

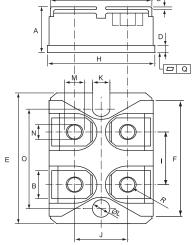
# **Benefits**

- Unipolar rectifier
- Zero switching loss
- Smaller heat sink
- Parallel devices without thermal runaway
- Higher efficiency

# **Applications**

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Power factor correction
- Diode snubber
- Automotive
- induction heating
- Welding equipment





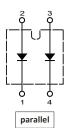
# **Maximum Ratings**

Operating Junction Temperature : -55  $^{\circ}\text{C}$  to +175  $^{\circ}\text{C}$ 

Storage Temperature : -55  $^{\circ}$ C to +175  $^{\circ}$ C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×50-065P3B	650V	650V

Maximum Rating	Symbol	Conditions	Value	Unit
Continuous forward current (per diode)	I <sub>F</sub> T <sub>C</sub> =135 °C		50	
Surge non-repetitive forward current	I <sub>FSM</sub>	$T_{C}$ =25 °C, $t_{p}$ =8.3 ms	400	
sine halfwave (per diode)	·F3IVI	T <sub>C</sub> =150 °C, t <sub>p</sub> =8.3 ms	250	Α
Non-repetitive peak forward current	I <sub>F,max</sub>	$T_{C}$ =25 °C, $t_{p}$ =10 $\mu$ s	1600	
(per diode)		$T_{C}$ =150 °C, $t_{p}$ =10 $\mu$ s	1000	
Repetitive peak reverse voltage	$V_{RRM}$	T <sub>j</sub> =25 °C	650	V
Isolation voltage between All Terminals and Baseplate	V <sub>iso</sub>	50/60 Hz, t=1min I <sub>ISOL</sub> ≤ 1mA	2500	V
Mounting torque		To heatsink	1.3	Nm
modifieng torquo		To terminal	1.1	1,111



DIMENSIONS						
	INCHES		M	М		
	MIN	MAX	MIN	MAX		
Α	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
E	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	1.008	25.30	25.60		
- 1	0.579	0.602	14.70	15.30		
J	0.492	0.516 12.50		13.10		
K	0.161	0.169 4.10		4.30		
L	0.161	0.169	0.169 4.10			
М	0.181	0.197 4.60		5.00		
N	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05	0.10		
R	M4*8					





## **Electrical Characteristics**, at T<sub>i</sub>=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Cumb al	Conditions	Values			
	Symbol	Conditions	min.	typ.	max.	Unit
DC blocking voltage	V <sub>DC</sub>		650	-	-	
	V <sub>F</sub>	I <sub>F</sub> =50A, T <sub>j</sub> =25 °C	-	1.5	1.7	V
Diode forward voltage		I <sub>F</sub> =50A, T <sub>j</sub> =175 °C	-	1.9	2.2	
	1_	V <sub>R</sub> =650V, T <sub>j</sub> =25 °C	-	30	60	
Reverse current	I <sub>R</sub>	V <sub>R</sub> =650V, T <sub>j</sub> =175 °C	-	60	250	$\mu$ A

#### AC Characteristics (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	Q <sub>rr</sub>	V <sub>R</sub> =400V, T <sub>j</sub> =25 °C	-	68	-	nC
Total capacitance	С	V <sub>R</sub> =1V, f=1 MHz T <sub>j</sub> =25 °C	-	2105	-	pF
		V <sub>R</sub> =200V, f=1 MHz T <sub>j</sub> =25 °C	-	240	-	
		V <sub>R</sub> =400V, f=1 MHz T <sub>j</sub> =25 °C	-	183	-	

### Thermal Characteristics (per diode)

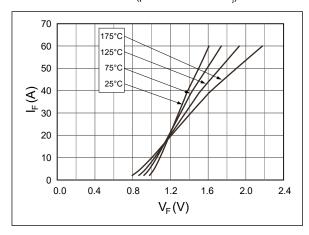
Static Characteristics	Symbol	Values	
Static Gharacteristics	Symbol	typ.	Unit
Thermal resistance from junction to case	$R_{ heta  JC}$	0.28	°C/W



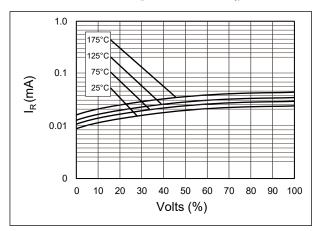


#### **Typical Performance**

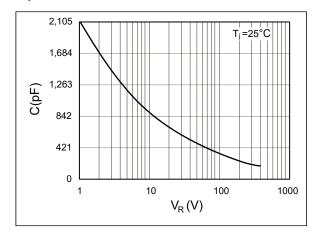
#### Forward Characteristics (parameterized on T<sub>i</sub>)



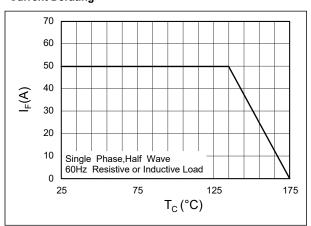
#### Reverse Characteristics (parameterized on Tj)



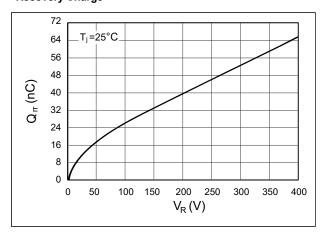
#### Capacitance



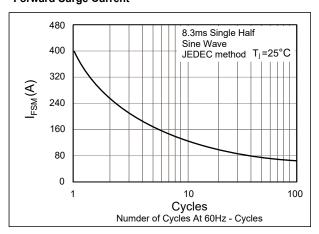
#### **Current Derating**



#### **Recovery Charge**



## Forward Surge Current





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